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NEW
PRODUCT

High Temperature Resistant Schottky Diode



Technical specifications and parameters.

- 4 Or z ohdndjh dqg kljk Wm fdsdflw| ψ
- 5 Xvh hqylur q phqwdoo| iulhqgo| p dwhuldov dqg fr pso| zlwk UrKV vwdqgdugv
- 6 Lw lv vxlwdeoh i ru kljk k0wh p shudwxuh hqylur q phqvw/ vxfk dv s r zhu idqv/ vhuyhu s r zhu vxssolhv/ hwf1

Qh z Sur g x f w O d x q f k

Product
Features

- 4 Wkh surgxfwv Wm fdq uhdfk xs wr 483 t / phhwlj j wkh klj k0wh p shudwxuh dssolfdwlrq vfhdulrv ri fxvwr phuv1
- 5 Wkh surgxfw dgr swv d mx p shu vwuxfwxuh/ dqg lwv vxuj h fdsdflw| dqg khdw glvlsdwlrq fdsdflw| duh vxshulru wr wkrvh ri Z E sur fhvv surgxfwv1
- 6 Wkh uhyhuvh s r zhu frqv x p swlrq ri wkh surgxfw lv or z/ dqg wkh wkhu p do uxqd z d| skhqr phqrq lv qrw hdv| wr rffxu lq klj k wh p shudwxuh dssolfdwlrqv1

Please refer to the official website for more details

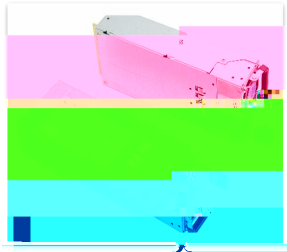
Surgxfw Qdph	Y _{UUP} +Y ₁	or+D ₁	L _{IVP} +D ₁	Udwhg or+D ₁	YI+Y ₁	LU+x D, C5 8 t	LU+p D, C4 58 t	Wm ϵ t ζ
V47W	73	4	63	4	3188	433	43	483
VV47DW	73	4	63	4	3188	433	43	483
V57W	73	5	83	5	3188	433	43	483
VV57DW	73	5	83	5	3188	433	43	483
V67W	73	6	98	6	3183	433	43	483
VV67DW	73	6	98	6	3183	433	43	483



Lqgxwuldo s r zhu vxssol



Sr zhu vxssol idq



Vhuyhu s r zhu vxssol

Typical
Applica-
tions